

# élantec

HIGH PERFORMANCE ANALOG INTEGRATED CIRCUITS

## EL2223/EL2223C

Dual, 500 MHz High Speed, Operational Amplifier

ELANTEC INC

T-79-07-20

EL2223/EL2223C

### Features

- Wide gain bandwidth—500 MHz
- High slew rate—350 V/ $\mu$ s
- High power bandwidth ( $\pm 10 V_{out}$ ) 5.5 MHz
- Large open loop gain 83 dB
- Low power—5 mA/amplifier
- Low input offset—0.5 mV typ.
- Wide supply voltage range  $V_s = \pm 5V$  to  $\pm 15V$
- Output short circuit protected

### Applications

- High performance active filters
- Video and pulse amplifiers
- Local area networks
- Wideband amplifiers
- Replace two HA2540s

### Ordering Information

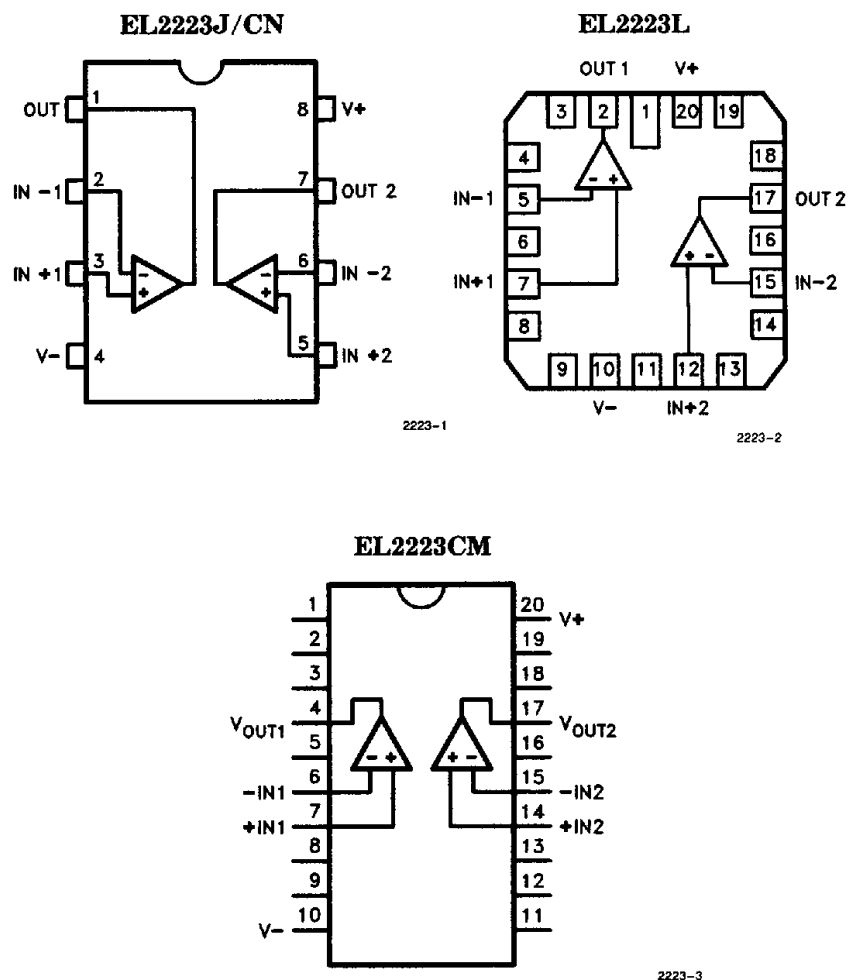
Part No.	Temp. Range	Package	Outline#
EL2223CJ	0°C to +75°C	CerDIP	MDP0010
EL2223CN	0°C to +75°C	P-DIP	MDP0031
EL2223J	-55°C to +125°C	CerDIP	MDP0010
EL2223J/883B	-55°C to +125°C	CerDIP	MDP0010
EL2223L/883B	-55°C to +125°C	LCC	MDP0007
EL2223CM	0°C to +75°C	SOL	MDP0027

### General Description

The EL2223 monolithic dual operational amplifier is an extension of Elantec's position in high speed analog products. This patented amplifier features 350 V/ $\mu$ s slew rate, a 500 MHz gain bandwidth gain-of-10 stable, along with an excellent speed power relationship. The dual 500 MHz EL2223 consumes only 10 mA, making it ideal for HA2540 type applications. The EL2223 has short-circuit-protected outputs and will operate from  $\pm 5V$  to  $\pm 15V$ . It is fabricated using Elantec's complementary bipolar process which allows both fast PNP and NPN transistors to be manufactured on a single chip.

Elantec's products and facilities comply with MIL-STD-883 Revision C, MIL-I-45208A, and other applicable quality specifications. For information on Elantec's military processing, see Elantec document, QRA-2: "Elantec's Military Processing, Monolithic Integrated Circuits".

### Connection Diagrams



This product covered under U.S. Patent No. 4,837,523

1

July 1991 Rev B

**EL2223/EL2223C**

ELANTEC INC

**Dual, 500 MHz High Speed, Operational Amplifier****Absolute Maximum Ratings** ( $T_A = 25^\circ\text{C}$ )

Voltage between V+ and V-	35V	Storage Temperature Range	-65°C to +150°C
Differential Input Voltage	±6V	Maximum Junction Temperature	
Internal Power Dissipation	See Curves	CerDIP, LCC	175°C
Peak Output Current	Short Circuit Protected	Plastic DIP, SOL	150°C
Output Short Circuit Duration (Note 1)	Continuous	Lead Temperature	
Operational Temperature Range		DIP Package	300°C
EL2223	-55°C to +125°C	SOL Package	
EL2223C	0°C to +75°C	Vapor Phase (60 seconds)	215°C
		Infrared (15 seconds)	220°C

**Important Note:**

All parameters having Min/Max specifications are guaranteed. The Test Level column indicates the specific device testing actually performed during production and Quality Inspection. Elantec performs most electrical tests using modern high-speed automatic test equipment, specifically the LTX77 Series system. Unless otherwise noted, all tests are pulsed tests, therefore  $T_J = T_C = T_A$ .

Test Level	Test Procedure
I	100% production tested and QA sample tested per QA test plan QCX0002.
II	100% production tested at $T_A = 25^\circ\text{C}$ and QA sample tested at $T_A = 25^\circ\text{C}$ , $T_{MAX}$ and $T_{MIN}$ per QA test plan QCX0002.
III	QA sample tested per QA test plan QCX0002.
IV	Parameter is guaranteed (but not tested) by Design and Characterization Data.
V	Parameter is typical value at $T_A = 25^\circ\text{C}$ for information purposes only.

**DC Electrical Characteristics**  $V_S = \pm 15\text{V}$ ;  $R_L = 2\text{ k}\Omega$ , unless otherwise specified

Parameter	Description	Temp	EL2223				EL2223C				Units
			Min	Typ	Max	Test Level	Min	Typ	Max	Test Level	
V <sub>OS</sub>	Offset Voltage	+25°C		0.5	5	I		0.5	5	I	mV
		Full			8	I			8	III	mV
TCV <sub>OS</sub>	Average Offset Voltage Drift	Full		3		V		3		V	μV/°C
I <sub>B</sub>	Bias Current	+25°C		1.5	4	I		1.5	4	I	μA
		Full			6	I			6	III	μA
I <sub>OS</sub>	Offset Current	+25°C		0.2	2	I		0.2	2	I	μA
		Full			3	I			3	III	μA
R <sub>IN</sub>	Input Resistance	+25°C		6		V		6		V	kΩ
C <sub>IN</sub>	Input Capacitance	+25°C		1		V		1		V	pF
V <sub>CM</sub>	Common Mode Input Range	Full	±10	±12		I	±10	±12		II	V
e <sub>IN</sub>	Input Noise Voltage (f = 1 kHz, R <sub>G</sub> = 0Ω)	+25°C		7		V		7		V	nV/√Hz
A <sub>VOL</sub>	Large Signal Voltage Gain (Notes 2, 3)	+25°C	20k	40k		I	20k	40k		I	V/V
		Full	10k			I	10k			III	V/V

ELANTEC INC

# EL2223/EL2223C

## Dual, 500 MHz High Speed, Operational Amplifier

EL2223/EL2223C

### DC Electrical Characteristics $V_S = \pm 15V$ ; $R_L = 2 k\Omega$ , unless otherwise specified — Contd.

Parameter	Description	Temp	EL2223				EL2223C				Units
			Min	Typ	Max	Test Level	Min	Typ	Max	Test Level	
CMRR	Common-Mode Rejection Ratio (Note 4)	Full	70	90		I	70	90		II	dB
$V_O$	Output Voltage Swing	Full	$\pm 11$	$\pm 12.5$		I	$\pm 11$	$\pm 12.5$		II	V
$I_{SC}$	Short Circuit Current	+25°C		$\pm 50$	$\pm 70$	I		$\pm 50$	$\pm 70$	I	mA
$R_O$	Output Resistance	+25°C		40		V		40		V	$\Omega$
$I_s$	Supply Current	Full		9.5	13	I		9.5	13	II	mA
PSRR	Power Supply Rejection Ratio (Note 5)	Full	70	90		I	70	90		II	dB

### AC Electrical Characteristics $V_S = \pm 15V$ ; $R_L = 2 k\Omega$ , unless otherwise specified

Parameter	Description	Temp	EL2223				EL2223C				Units
			Min	Typ	Max	Test Level	Min	Typ	Max	Test Level	
$f_u$	Open Loop Unity Bandwidth (Note 6)	+25°C		500		V		500		V	MHz
FPBW	Full Power Bandwidth (Notes 2, 7)	+25°C	3.98	5.5		I	3.98	5.5		I	MHz
$t_r$	Rise Time (Note 8)	+25°C		7		V		7		V	ns
OS	Overshoot (Note 8)	+25°C		30		V		30		V	%
SR	Slew Rate (Note 8)	+25°C	250	350		I	250	350		I	V/ $\mu$ s
$t_s$	Settling Time (Notes 9, 10) 10V Step to 0.05%	+25°C		330		V		330		V	ns
Ch $S_p$	Channel Separation ( $f = 10$ MHz)			70		V		70		V	dB

Note 1: A heat sink is required to keep the junction temperature below absolute maximum when the output is shorted.

Note 2:  $V_O = \pm 10V$ .

Note 3:  $R_L = 2 k\Omega$ .

Note 4: Two tests are performed.  $V_{CM} = 0V$  to +10V and  $V_{CM} = 0V$  to -10V.

Note 5: Two tests are performed.  $V_+ = 15V$ , and  $V_-$  is changed from -5V to -15V.  $V_- = -15V$ , and  $V_+$  is changed from +5V to +15V.

Note 6:  $V_O = 100$  mV.

Note 7: Full Power Bandwidth guaranteed based on slew rate measurement using:  $FPBW = \text{Slew Rate} / 2 \pi V_{peak}$ .

Note 8: Refer to Test Circuit section of data sheet.

Note 9: Settling time measurement are made with techniques in the following reference: "Take The Guesswork Out of Settling-Time Measurements," EDN September 19, 1985.

Note 10:  $A_V = +10$ ,  $R_L = 2 k\Omega$ .



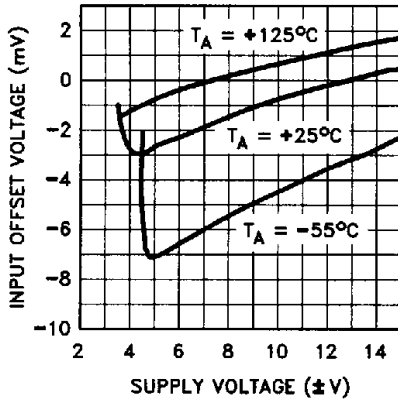
# EL2223/EL2223C

ELANTEC INC

Dual, 500 MHz High Speed, Operational Amplifier

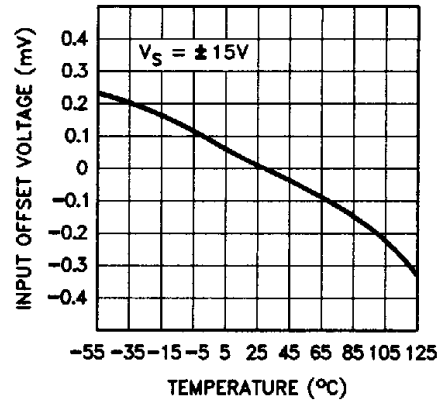
## Typical Performance Curves

Input Offset Voltage vs Supply Voltage



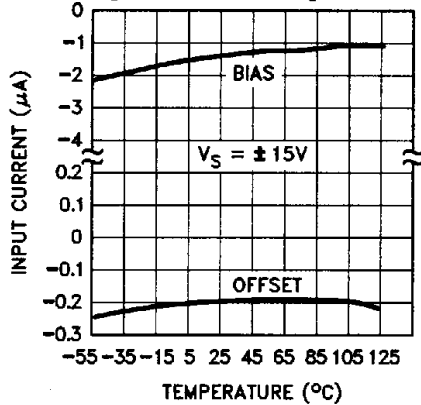
2223-4

Normalized Input Offset Voltage vs Temperature



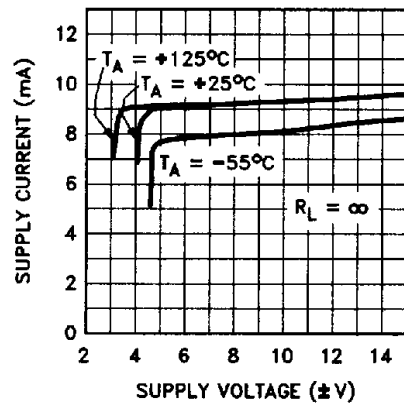
2223-5

Input Current vs Temperature



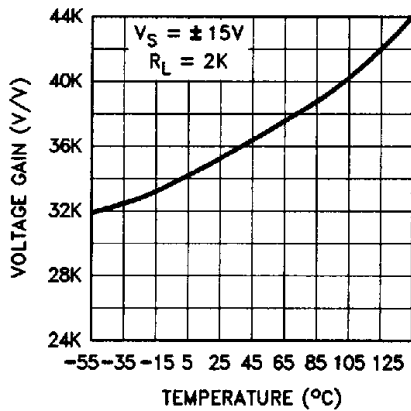
2223-6

Supply Current vs Supply Voltage



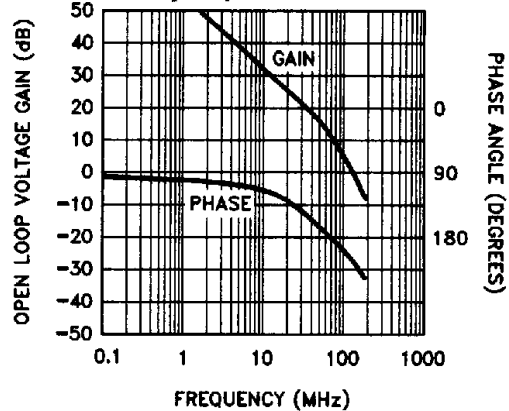
2223-7

Voltage Gain vs Temperature



2223-8

Open Loop Voltage Gain vs Frequency



2223-9

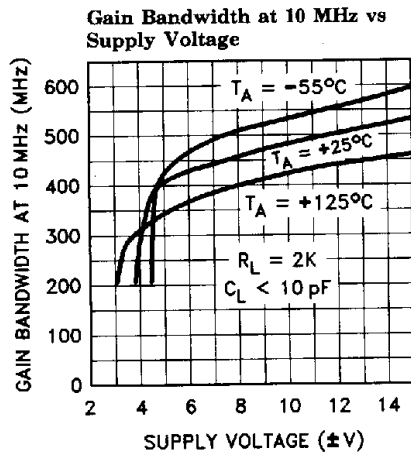
ELANTEC INC

# EL2223/EL2223C

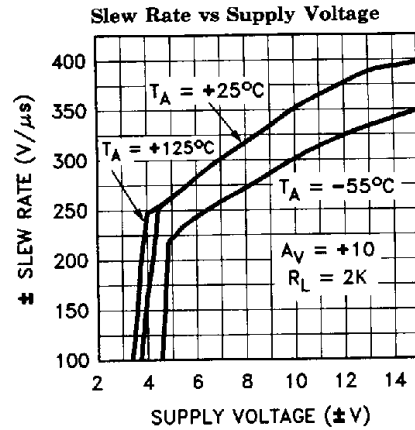
## Dual, 500 MHz High Speed, Operational Amplifier

EL2223/EL2223C

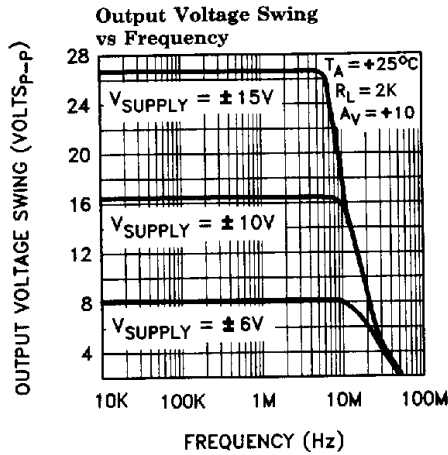
### Typical Performance Curves — Contd.



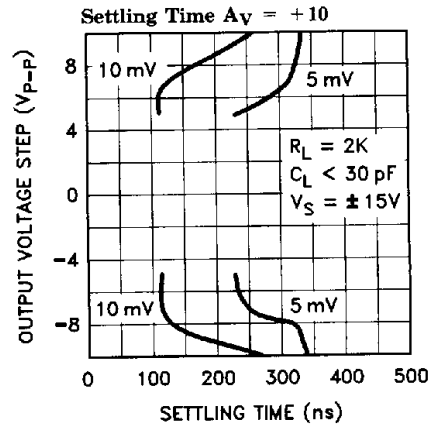
2223-10



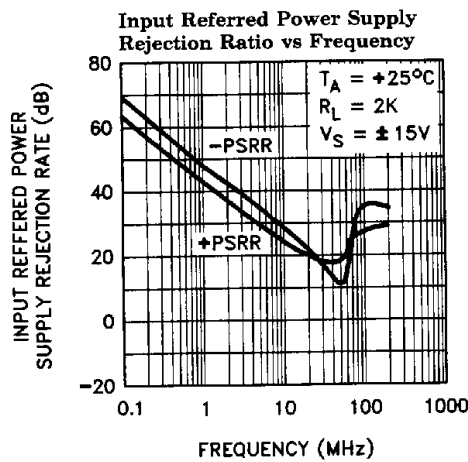
2223-11



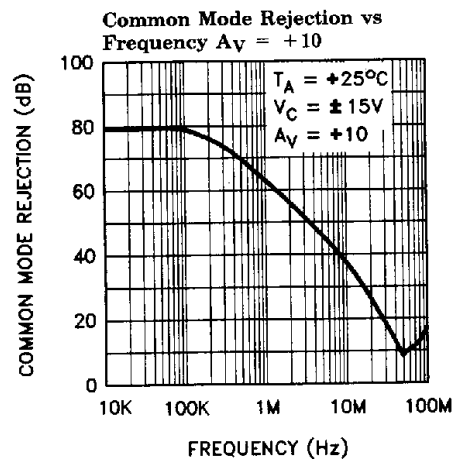
2223-12



2223-13



2223-14



2223-15

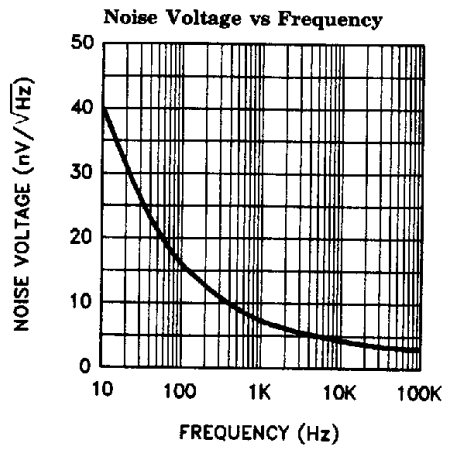
EL2223/EL2223C

# EL2223/EL2223C

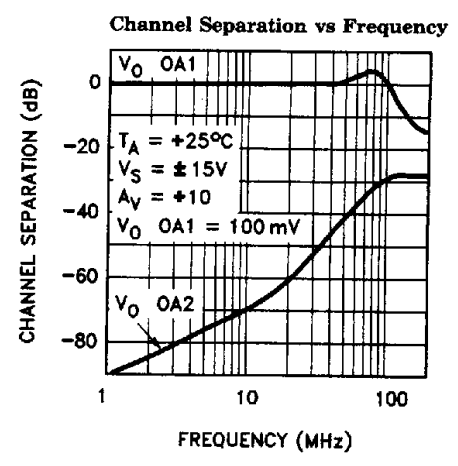
ELANTEC INC

## Dual, 500 MHz High Speed, Operational Amplifier

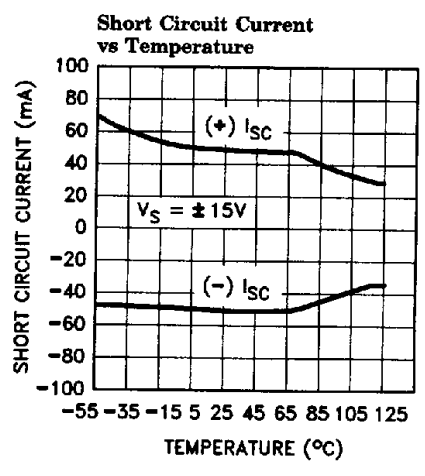
### Typical Performance Curves — Contd.



2223-16

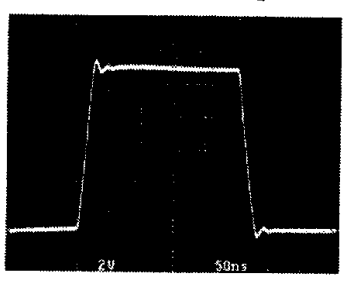


2223-17



2223-18

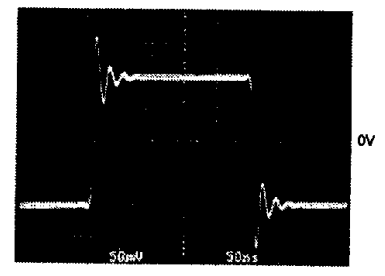
### Large Signal Response



$A_V = +10$   
 $V_{IN} = \pm 0.5\text{V}$   
 $V_O = \pm 5\text{V}$   
 $R_L = 2\text{k}$

2223-19

### Small Signal Response



$A_V = +10$   
 $V_{IN} = \pm 10 \text{ mV}$   
 $V_O = \pm 100 \text{ mV}$   
 $R_L = 2\text{k}$

2223-20

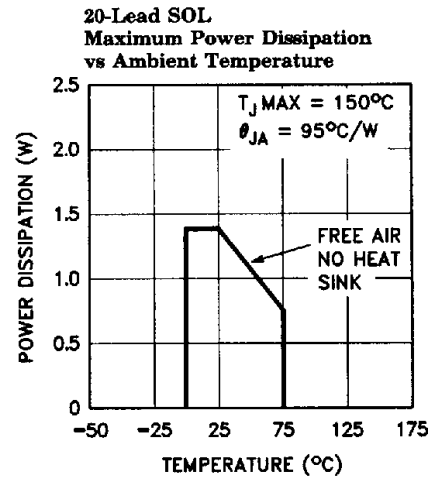
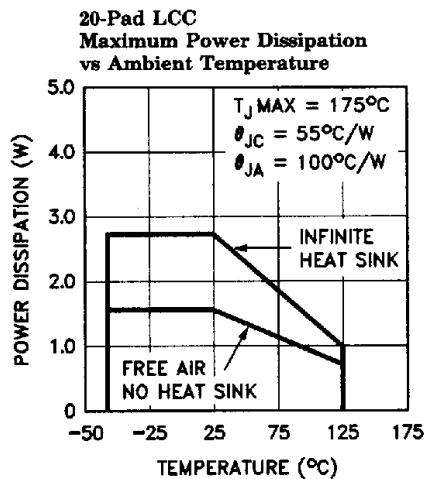
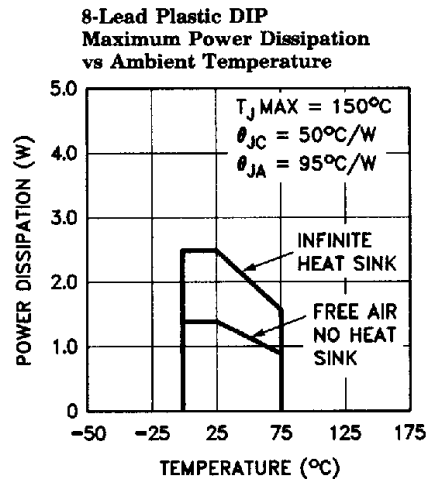
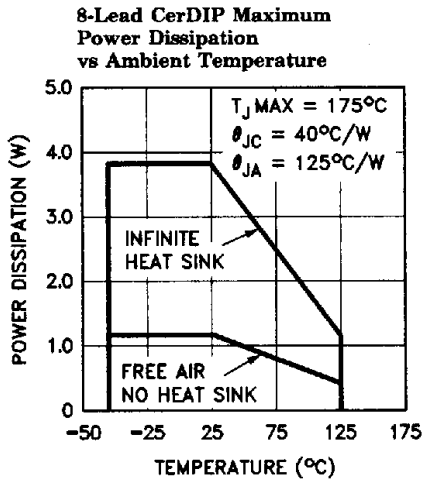
ELANTEC INC

# EL2223/EL2223C

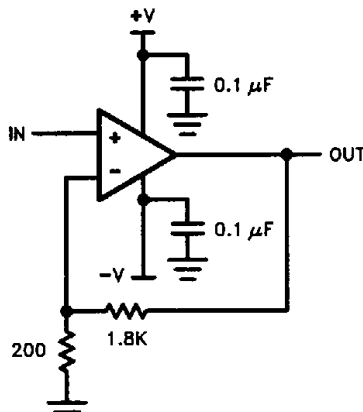
## Dual, 500 MHz High Speed, Operational Amplifier

EL2223/EL2223C

### Typical Performance Curves — Contd.



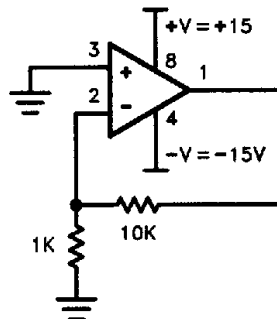
### Test Circuit



$A_V = +10$   
 $C_L \leq 10 \text{ pF}$  Scope Probe

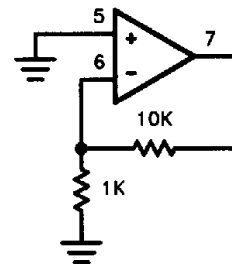
2223-27

### Burn-In Circuit



Pin numbers are for the 8-Lead CerDIP.  
 Burn-in circuit is identical for all package types.

2223-28

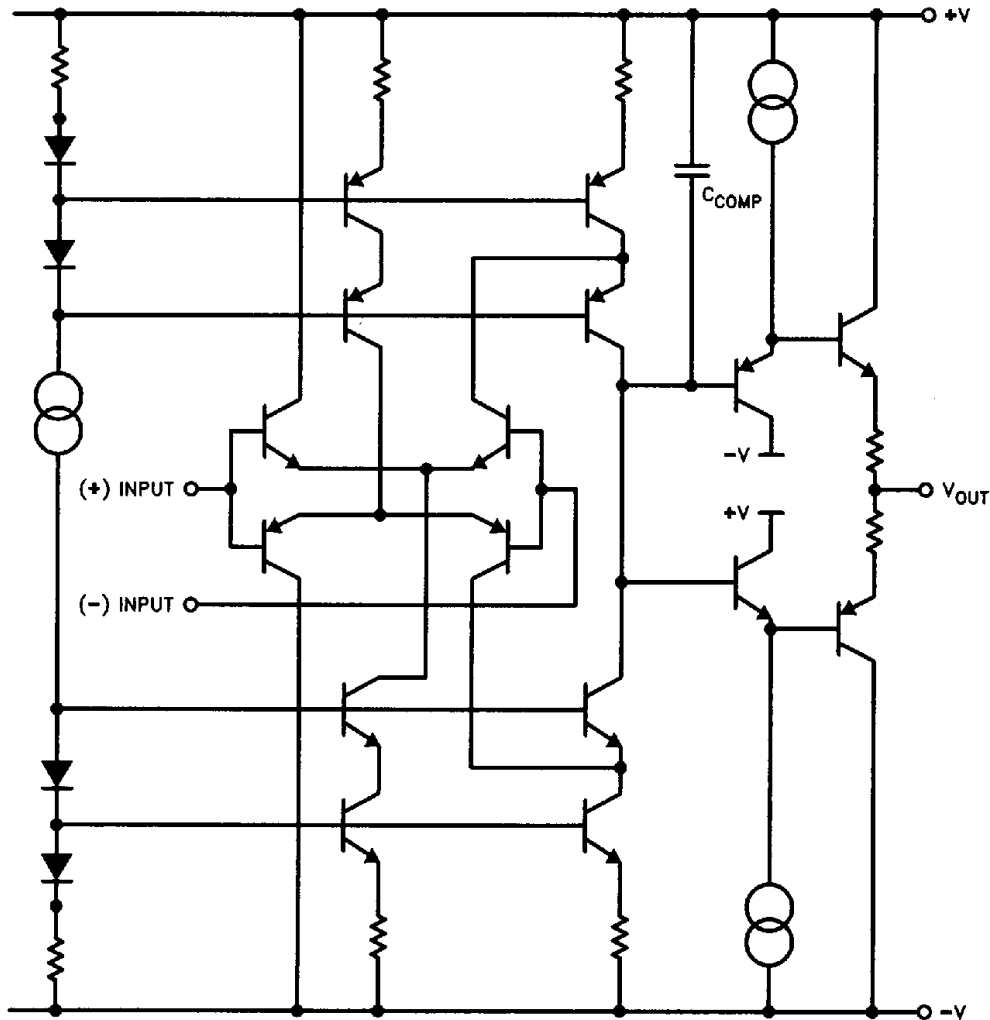


2223-29

1

**EL2223/EL2223C**

ELANTEC INC

**Dual, 500 MHz High Speed, Operational Amplifier****Simplified Schematic** (one amplifier)

2223-25



ELANTEC INC

**EL2223/EL2223C**  
*Dual, 500 MHz High Speed, Operational Amplifier*

EL2223/EL2223C

**EL2223 Macromodel**

```

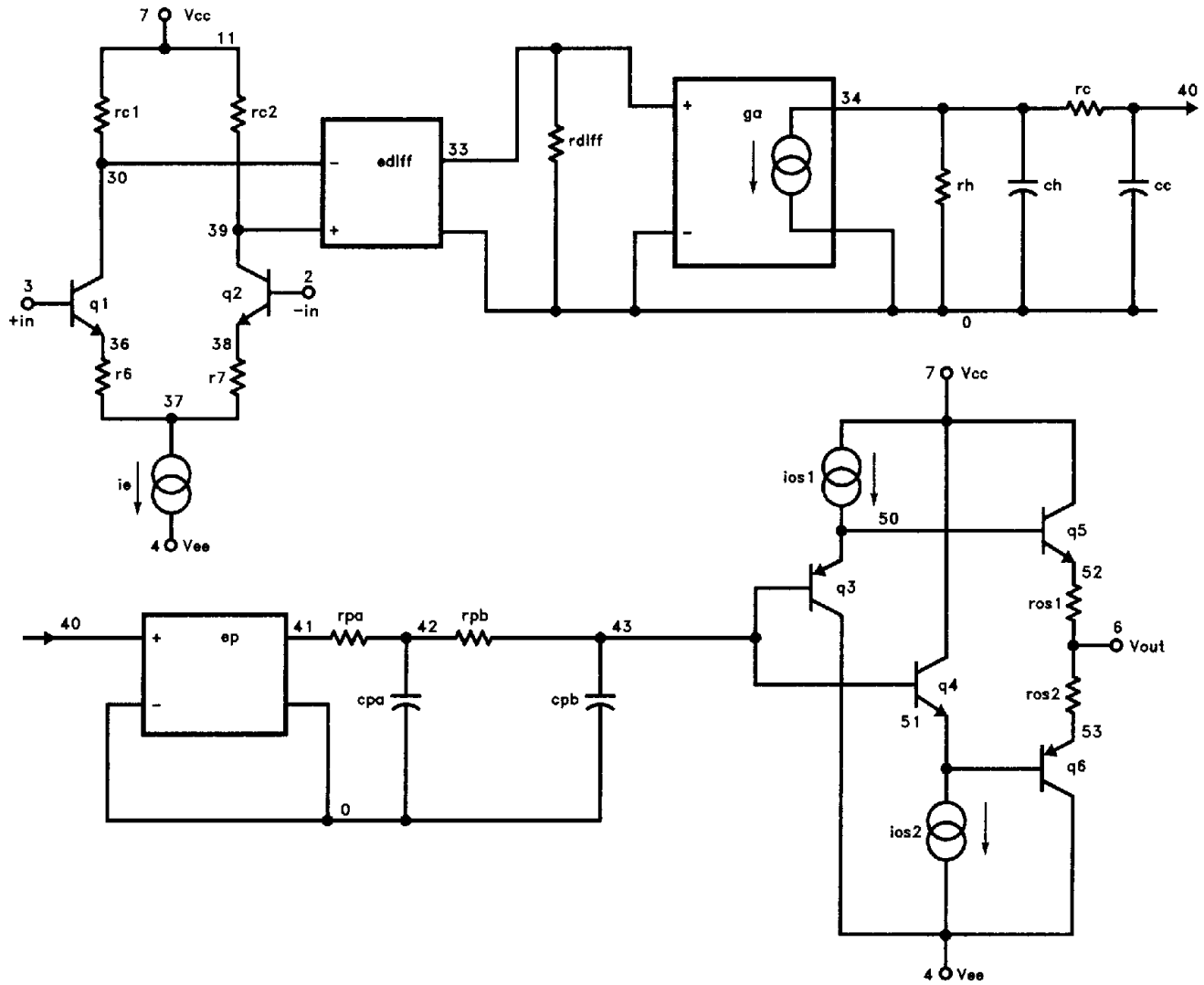
* Connections:      + input
*                  |
*                  | - input
*                  |
*                  | + Vsupply
*                  |
*                  | - Vsupply
*                  |
*                  | output
*                  |
.subckt M2233      3      2      7      4      6
* Input stage
ie 37 4 2mA
r6 36 37 60
r7 38 37 60
rc1 7 30 75
rc2 7 39 75
q1 30 3 36 qn
q2 39 2 38 qna
ediff 33 0 39 30 7.25
rdiff 33 0 1Meg
* Compensation Section
ga 0 34 33 0 2.6m
rh 34 0 3Meg
ch 34 0 1.5pF
rc 34 40 600
cc 40 0 7pF
* Poles
ep 41 0 40 0 1
rpa 41 42 75
cpa 42 0 25pF
rpb 42 43 50
cpb 43 0 15pF
* Output Stage
ios1 7 50 1.25mA
ios2 51 4 1.25mA
q3 4 43 50 qp
q4 7 43 51 qn
q5 7 50 52 qn
q6 4 51 53 qp
ros1 52 6 25
ros2 6 53 25
* models
.model qn npn (is = 800.0E-18 bf = 250 tf = 0.2nS)
.model qna npn (is = 864E-18 bf = 300 tf = 0.2nS)
.model qp pnp (is = 800E-18 bf = 60 tf = 0.2nS)
.ends

```

1

**EL2223/EL2223C**

ELANTEC INC

**Dual, 500 MHz High Speed, Operational Amplifier****EL2223 Macromodel — Contd.**

2223-30